Quantum size effects in thermodynamic superconducting properties of ultra thin films

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By using multi-bands BCS theory, we have calculated the superconductivity energy gap and the critical temperature of a thin-film metallic superconductor. The thermodynamic superconducting characteristics such as critical magnetic field, specific heat, as well as the tunneling conductance are investigated for varying film thickness and temperature. We find the oscillation of thermodynamic superconducting properties with the film thickness, including the thermodynamic critical field H_c , the specific heat of normal, superconducting state, and position of the differential tunneling conductance peak. The two universal constants the nth sub-band energy gap Δ_n at temperature T=0K over k_BT_c , and the specific heat jump at T_c over normal state specific heat at T_c are independent of the film thickness. Their values are the same as in the bulk superconductor.

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Quantum size effects (QSE) in superconductors have been a very attractive topic after some theoretical investigations of the superconducting transition temperature T_c and energy gap for thin films.[1] Some theoretical [2, 3, 4] and experimental [5, 6, 7, 8] works have reported that several quantities were modulated by QSE, including electronic structure, electron-phonon interaction, resistivity, Hall conductivity, work function, surface energy and superconductivity critical temperature. In a metal film on a semiconductor substrate, the conduction electrons are confined by the vacuum on one side and the metal-semiconductor interface on the others.[9] QSE and the simple stability of metal thin films on a supporting substrate have been discussed in several papers.[11, 12, 13]

The report by Guo et al. is the first definitive and quantitative demonstration of T_c oscillation with Pb film thickness as well as the normal state conductance. [11] Using atomically uniform film of lead with exactly known numbers of atomic layers deposited on a silicon (111) surface, Guo et al. observed oscillations in T_c that correlated well with the confined electronic structure and recently they demonstrated that film thickness can indeed affect superconductivity behaviors. It has been found that when the thickness of a film is reduced to the nanometer scale, the film's surface and interface will confine the motion of the electrons, leading to the formation of discrete electronic states known as quantum well states (QWS).[13] QWS have already been observed in thin metallic films.[10] And they change the overall electronic structure of the thin film. At a tiny thickness, physical properties are thus expected to vary dramatically with the thickness. Very recently, Daejin et al. using a scanning tunneling spectroscopy study to show that both energy gap and transition temperature exhibit persistent oscillation without any suppression at ultra thin Pb films (5-18ML).[14]

Quantum oscillations can be understood by considering QSE in these systems.[13] The period is fixed for each system and equals one half of the bulk Fermi wavelength which is related to the average electron density and crystal structure.[12] Although lots physical properties modulated by QSE in thin films have been revealed, the thermodynamic superconducting characteristics such as the specific heat, the thermodynamic critical field, tunneling conductance as the function of thickness and other parameters have not been reported. In this paper, by using the multi-band superconductivity theory which improves previous theory about QSE in superconductor film, we present the results of thermodynamic superconducting properties of ultra-thin metallic films.

From theoretical point of view,[1] the resonance and the strong thickness dependence of T_c are the characteristic features of a thin film superconductivity. The quantization of the transverse motion of the electron in the film leads to an increase of T_c with decreasing film thickness, arising essentially from an enhanced effective BCS pairing interaction.[15] In the previous calculations,[1] the phonon modes were assumed to be the same as in bulk material and only the one dimensional quantum confinement effect of electrons were considered. Reference 16 considered the phonon dispersion in a thin film undergoing substantial modification compared with the bulk system with quantization of phonon spectrum. They found the resonant shape of superconductor transition temperature T_c arises from both electronic and phonon confinements. Because of the quantization of both electron and phonon energies, the effective electronelectron interaction modified by the quantized phonon is different from the interaction arising from the bulk phonon.[17] They found some fine structures in the energy gap and critical temperature by comparing with the bulk phonon model.[16] However experimentally, no evidence of such fine structure from phonon confinement was found.[11, 14] Thus, we will evaluate the thermodynamic characteristics by the same multi-band BCS theory, but neglect the phonon quantization effects.

We will start our model by taking into account of a realistic boundary condition. The thin film is confined in the x direction with geometric thickness Nt. N is the thin film layer and t is the average inter-layer distance. Because of the finite potential barriers at the interface of thin film with Si substrates and vacuum, we will expand the film boundaries slightly to allow certain amount of charge spillage at two interfaces.[18, 19] For simplicity, we take charge spillage distances as the same at two interfaces. So the physical thickness is $d = Nt + 2\Delta_0$.

The multi-band BCS Hamiltonian of the system is given by [16]

$$H = \sum_{nk\sigma} \xi_n(k) c_{kn\sigma}^{\dagger} c_{kn\sigma}$$

$$+ \sum_{kk'\sigma} \sum_{nm} V_{kk'}^{nm} c_{k'm\sigma}^{\dagger} c_{-k'm-\sigma}^{\dagger} c_{kn\sigma} c_{-kn-\sigma}, \quad (1)$$

where $c_{kn\sigma}^{\dagger}$ is the electron operator in the nth sub-band with spin σ , $\xi_n(k) = \epsilon_n(k) - \mu$ the electron energy in the sub-band n measured from the chemical potential μ , and $V_{kk'}^{nm}$ the attractive interaction between nth sub-band and mth sub-band is given by [18]

$$V_{kk'}^{nm} = -\frac{J}{L^2} \left[\frac{1}{d} (1 + \frac{\delta_{nm}}{2}) - \frac{b}{d^2} \right], \tag{2}$$

Only if $|\xi_n(k)|$ and $|\xi_n(k')| < \hbar \omega_D$. J is the interaction constant and L is the periodic distance in the y and z directions. $\hbar\omega_D$ is the Debye energy. The constant b comes from the integral cutoff.

In the weak-coupling approximation, we have the superconducting energy gap for the nth sub-band given by the gap function using the mean field method

$$\Delta_{nk}(T) = -\sum_{m,k'} \frac{\Delta_{mk'}(T)}{2E_{mk'}} V_{kk'}^{nm} \tanh(\frac{\beta E_{m,k'}}{2}), \quad (3)$$

where $E_{mk} = (\xi_{mk}^2 + \Delta_{mk}^2)^{1/2}$. The off-diagonal terms in the summation reflect the possibility of transition of the electron pair from one subband into another as the result of interaction with the confined phonons. Integration over k gives the gap function of the nth sub-band at T. After some derivation, we arrive at the gap equation at zero temperature

$$\Delta = \hbar \omega_D \sinh^{-1}\left(\frac{Ka}{\gamma(1 - b/a) + \frac{1}{2}}\right),\tag{4}$$

The critical transition temperature is

$$k_B T_c = 1.14 \hbar \omega_D \exp(-\frac{Ka}{\gamma (1 - b/a) + \frac{1}{2}}).$$
 (5)

where we assume the integral range of k' in Eq. (3) are the same for each subband. K is a special interaction

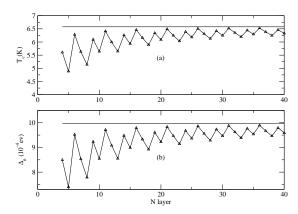


FIG. 1: (a) The critical temperature and (b) the superconducting energy gap of the nth occupied subband versus superconducting film layers N, compared with bulk values (straight line). Here we take Fermi wave length $k_f=1.57 \mathring{A}^{-1}$, interaction constant $k = 1.5 \text{Å}^{-1}$, Debye energy $\hbar \omega_D = 0.01 ev$, with other parameters as b = 1Å, t = 2.8Å and $\Delta_0 = 0.7$ Å. All the following graphs are with the same parameters. In our models, the energy gap is independent of each subband.

constant given by $K = \pi \hbar^2/mJ$ and γ is the highest occupied sub-band, given by the integer part of dk_f/π . The Fermi level only shifts slightly within 1% of its bulk value at very thin thickness.[19] So in our numerical calculation, we choose the Fermi wave vector as a constant, independent of film thickness. These results are similar as in Ref. 18. The bulk values of energy gap and transition temperature are given as:[18]

$$\Delta^{bulk} = \hbar \omega_D \sinh^{-1}(\frac{K\pi}{k_f}), \tag{6}$$

$$k_B T_c^{bulk} = 1.14\hbar\omega_D \exp(-\frac{K\pi}{k_f}). \tag{7}$$

In Fig. 1, we compare the results of energy gap at T = 0K and the superconducting transition temperature T_c with those of bulk values. We could see that the gap and T_c all oscillate with a period of 5 atomic layers. This can be understood by considering that the ratio of half Fermi wave length versus atomic layer distance is roughly 2/3. If the layer thickness changes continuously, the oscillation period is known to be $\lambda_f/2$. The modulating of these two quantities will lead the oscillation pattern differ by 5ML. We also notice that the oscillation amplitude will decay with increasing of the film thickness. But all these oscillation values are smaller than bulk values. This is in accord with several experimental results.[11, 14] And the most interesting thing is that the energy gap Δ_n oscillate the same way as T_c , which leads to the universal constant $\Delta_n/k_BT_c=1.76$. This constant is the same as

the bulk values. Similar conclusions have been reached by experiments in ultra thin Pb films,[14] but a higher universal constant of 4.4 is obtained. Because Pb has a very strong electron phonon coupling, the weak coupling BCS theory used here is not quite applicable.

The Gibbs free energy, the thermodynamic critical field H_c , the entropy and the specific heat per volume in a superconducting film are given, respectively by

$$F = F_0 + \frac{k_B T}{V} \sum_{mk} \ln[f_{mk}(1 - f_{mk})], \tag{8}$$

$$-\frac{1}{8\pi}H_c^2 = \delta F(T) = -\frac{k_B T}{V} \sum_{mk} \ln[\frac{1 + \cosh(\beta E_{mk})}{1 + \cosh(\beta \xi_{mk})}],$$
(9)

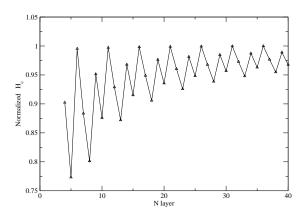


FIG. 2: The thermodynamic critical field H_c in the unit of bulk value (normalized H_c) as a function of film layers N in the unit of bulk values at the reduced temperature $T/T_c = 0.1$.

$$S = -\frac{2}{V} \sum_{mk} [(1 - f_{mk}) \ln(1 - f_{mk}) + f_{mk} \ln f_{mk}], \quad (10)$$

$$C_{v} = \frac{2\beta^{2}k_{B}}{V} \sum_{mk} f_{km} (1 - f_{km}) (E_{k}^{2} + \frac{1}{2}\beta \frac{\partial \Delta_{m}^{2}}{\partial \beta}), \quad (11)$$

where $f_{km} = [\exp(\beta E_{km}) + 1]^{-1}$ and $\beta = 1/k_B T$.

The thermodynamics critical field H_c is also shown in Fig. 2. We also find the similar oscillation of H_c with the the film layers N, although no experimental are available yet. The layer dependent H_c shows an oscillation amplitude of 22% of the bulk situation at 5 to 8ML and decay to the amplitude of 5% of the bulk H_c at thicker films. However, QSE on the perpendicular upper critical field

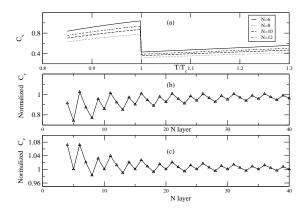


FIG. 3: (a) The variation of specific heat with reduced temperature T/T_c for different film thickness. The normalized specific heat versus film layers N at superconducting state $(T/T_c = 0.9)$ and at normal state (T=8k) is shown respectively in (b) and (c).

 H_{c2} in the ultra-thin lead film has been reported whose oscillation is out of phase with the H_c oscillation.[20]

The specific heat is also calculated with Eq. (11) at both superconductor and normal state. In Fig. 3(a), we show the specific heat as a function of reduced temperature λ ($\lambda \equiv /T_c$) at different films layers. We could see the jump of specific heat at critical temperature. Meanwhile, we also notice that although the specific heat both at normal and superconducting state oscillate with film thickness, the jump of specific heat at T_c divided by the normal state specific heat $[(C_s - C_n)/C_n]_{T_c}$ is another universal constant 1.42, and this constant is the same as in bulk situation. In Fig. 3(b) and 3(c), we can see that the specific heat at supercondcting state varies in the same way as T_c does. But its value could be slightly higher than the bulk case. For the specific heat in a normal state, it oscillate unsymmetrically around its bulk value. This oscillation behavior is different from others. Hopefully, all these results could be verified in future experiments.

The ratio of superconductor-normal tunneling differential conductance G_{SN} to normal tunneling differential conductance G_{NN} is

$$\frac{G_{SN}}{G_{NN}} = \int \frac{sign(\varepsilon)}{\sqrt{\varepsilon^2 - \Delta^2}} \frac{\partial f(\varepsilon + eV)}{\partial \varepsilon} d\varepsilon.$$
 (12)

The tunneling differential conductance versus bias voltage calculated at different film layers and different temperature from Eq. (12) are also shown in Fig. 4. The peak of the conductance is almost at $eV = \Delta_n$. Because in our model all the energy gaps of each sub-band are assumed to be the same, we could only find one peak in the

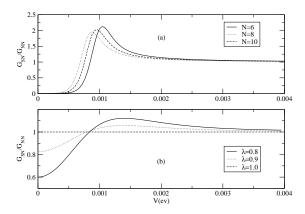


FIG. 4: $\frac{G_{SN}}{G_{NN}}$ as the function of applied voltage V (a) at different film thickness with T=1K and (b) for different reduced temperature λ with film layers N=7.

tunneling conductance. We also find that the position of the conductance peak oscillates with thickness. The reason for this kind of oscillation is due to the oscillation of energy gap Δ_n at different thicknesses. In Fig. 4(b), we can see that the peak is depressed at high temperature, because energy gap decreases with increasing temperature. Recently, Daejin *et al.* have already extracted energy gap from the measured conductance spectra to determine the transition temperature. [14]

In this paper, we apply multi-band BCS theory to calculate thermodynamic quantities and find their oscillations with the film thickness, including the thermodynamic critical field H_c , the specific heat at normal and superconducting state and the position of differential conductance peak. These oscillations are the manifestations of the QSE. But two universal constants $\Delta_n/k_BT_c=1.76$ and $[(C_s-C_n)/C_n]_{T_c}=1.42$ is independent of the film thickness, and their values are the same as in bulk situation. We hope that these interesting oscillations could all be observed experimentally in the future.

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 J. M. Blatt and C. J. Thompson, Phys. Rev. Lett. 10, 332 (1963); C. J. Thompson and J. M. Blatt, Phys. Lett.

- **5**, 6 (1963); V. Z. Kresin and B. A. Tavger, Sov. Phys. JETP **23**, 1124 (1966); B. A. Tavger and W. S. Kresin, Phys. Lett. **20**, 595 (1966).
- Z. Tesanovic, M. V. Jaric and S. Maekawa, Phys. Rev. Lett. 57, 2760 (1986); G. Govindaraj and V. Devanathan, Phys. Rev. B 34, 5904 (1986); N. Trivedi and N. W. Ashcroft, Phys. Rev. B 38, 12298 (1988); I. Vilfan and H. Pfnür, Eur. Phys. J. B 36, 281 (2003).
- D. Calecki, Phys. Rev. B 42, 6906 (1990).
- [4] F. K. Schulte, Surf. Sci. 55, 427 (1976); P. J. Feibelman, Phys. Rev. B 27, 1991 (1983); P. Saalfrank, Surface Science 274, 449 (1992); Giuliana Materzanini, Peter Saalfrank and Philip J. D. Lindan, Phys. Rev. B 63, 235405 (2001); C. M. Wei and M. Y. Chou, Phys. Rev. B 66, 233408 (2002).
- [5] B. G. Orr, H. M. Jaeger and A. M. Goldman, Phys. Rev. Lett. 53, 2046 (1984).
- [6] M. Jalochowski, E. Bauer, H. Knoppe and G. Lilienkamp, Phys. Rev. B 45, 13607 (1992); O. Pfennigstorf, A. Petkova, H. L. Guenter and M. Henzler, Phys. Rev. B 65, 045412 (2002); O. Pfennigstorf, A, Petkova, Z. Kallassy and H. Henzler, Eur. Phys. J. B. 30, 111 (2002).
- [7] T. Valla, M. Kralj, A. Siber, M. Milun, P. Pervan, P. D. Johnson and D. P. Woodruff, J. Phys. Condens. Matter 12, L477 (2000); D.-A. Luh, T. Miller, J. J. Paggel and T.-C. Chiang, Phys. Rev. Lett. 88, 256802 (2002); Yan-Feng Zhang, Jin-Feng Jia, Tie-Zhu Han, Zhe Tang, Quan-Tong Shen, Yang Guo, Z. Q. Qiu and Qi-Kun Xue, Phys. Rev. Lett. 95, 096802 (2005).
- [8] Yu. F. Ogrin, V. N. lutskii, M. V. Arifova, V. I. Kovalev, V. B. Sandomirskii, and M. I. Elinson, Sov. Phys. JETP, 26, 714 (1968); B. A. Tavger and V. Ya. Demikhovskii, Sov. Phys. Uspekhi, 11, 644 (1968).
- [9] Z. Zhang, Q. Niu and C.-K Shih, Phys. Rev. Lett. 80, 5381 (1998) and references therein.
- [10] T. Miller, A. Samsavar, G. E. Franklin and T. C. Chiang, Phys. Rev. Lett. 61, 1404 (1988).
- [11] Yang Guo, Yan-Feng Zhang, Xin-Yu Bao, Tie-Zhu Han, Zhe Tang, Li-Xin Zhang, Wen-Guang Zhu, E. G. Wang, Qian Niu, Z. Q. Qiu, Jin-Feng Jia, Zhong-Xian Zhao and Qi-Kun Xue, Science 306, 1905 (2004).
- [12] T.-C. Chiang, Science **306**, 1900 (2004).
- [13] T. C. Chiang, Surf. Sci. Rep. 39, 181 (2000).
- [14] Daejin Eom, S. Qin, M.-Y. Chou and C. K. Shih, Phys. Rev. Lett. 96, 027005 (2006).
- [15] V. Z. Kresin, Phys. Rev. B **25**, 157 (1982).
- [16] E. H. Hwang, S. Das Sarma and M. A. Stroscio, Phys. Rev. B 61, 8659 (2000).
- [17] J. C. Nabity and M. N. Wybourne, Phys. Rev. B 44, 8990 (1992); J. Seyler and M. N. Wybourne, Phys. Rev. Lett. 69, 1427 (1992).
- [18] Ming Yu, Myron Strongin and A. Paskin, Phys. Rev. B 14, 996 (1976).
- [19] P. Czoschke, H. Hong, L. Basile, T. C. Chiang, Phys. Rev. B 72, 075402 (2005); P. Czoschke, H. Hong, L. Basile, T. C. Chiang, Phys. Rev. B 72, 035305 (2005).
- [20] Xin-Yu Bao, Yan-Feng Zhang, Yupeng Wang, Jin-Feng Jia, Qi-Kun Xue, X. C. Xie, and Zhong-Xian Zhao, Phys. Rev. Lett. 95, 247005 (2005).